MOSFET – Single, N-Channel with ESD Protection, Small Signal, SC-75 and SC-89 20 V, 915 mA

Features

- Low R_{DS(on)} Improving System Efficiency
- Low Threshold Voltage, 1.5 V Rated
- ESD Protected Gate
- NV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free Packages are Available

Applications

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Management
- Portables like Cell Phones, PDAs, Digital Cameras, Pagers, etc.

MAXIMUM RATINGS (T_{.1} = 25°C unless otherwise stated)

| Parame | Symbol | Value | Units | | | | |
|---|--|---------------|-----------------|------|----|--|--|
| Drain-to-Source Voltage | V_{DSS} | 20 | V | | | | |
| Gate-to-Source Voltage | | | V _{GS} | ±6.0 | V | | |
| Continuous Drain | Steady State $T_A = 25^{\circ}C$ $T_A = 85^{\circ}C$ | | I _D | 915 | mA | | |
| Current (Note 1) | | | | 660 | | | |
| Power Dissipation (Note 1) | Steady State | | P _D | 300 | mW | | |
| Pulsed Drain Current | t _p = | -10 μs | I _{DM} | 1.3 | Α | | |
| Operating Junction and St | T _J , T _{STG} | –55 to 150 | °C | | | | |
| Continuous Source Currer | I _S | 280 | mA | | | | |
| Lead Temperature for Solo (1/8" from case for 10 s) | TL | 260 | °C | | | | |

THERMAL RESISTANCE RATINGS

| Parameter | Symbol | Value | Units |
|--|-----------------|-------|-------|
| Junction-to-Ambient - Steady State (Note 1) SC-75 / SOT-416 | $R_{\theta JA}$ | 416 | °C/W |
| SC-89 | | 400 | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

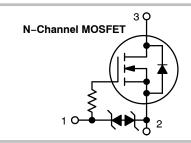
 Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces).



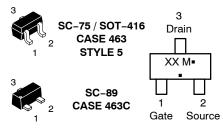
ON Semiconductor®

http://onsemi.com

| V _{(BR)DSS} | R _{DS(on)} TYP | I _D MAX |
|----------------------|-------------------------|--------------------|
| 20 V | 0.127 Ω @ 4.5 V | |
| | 0.170 Ω @ 2.5 V | 915 mA |
| | 0.242 Ω @ 1.8 V | 01011111 |
| | 0.500 Ω @ 1.5 V | |



MARKING DIAGRAM & PIN ASSIGNMENT



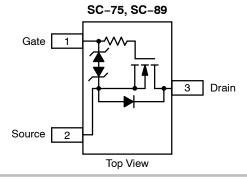
XX = Device Code

M = Date Code*

Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.



ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise stated)

| Parameter | Symbol | Test Cond | dition | Min | Тур | Max | Unit |
|--|--------------------------------------|---|-----------------------|------|-------|------|-------|
| OFF CHARACTERISTICS | • | | • | | • | | |
| Drain-to-Source Breakdown Voltage | V _{(BR)DSS} | $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ | | 20 | 26 | | V |
| Drain-to-Source Breakdown Voltage Temperature Coefficient | V _{(BR)DSS} /T _J | | | | 18.4 | | mV/°C |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{GS} = 0 V, V_{E}$ | _{OS} = 16 V | | | 100 | nA |
| Gate-to-Source Leakage Current | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$ | | | | ±1.0 | μΑ |
| ON CHARACTERISTICS (Note 2) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | $V_{GS} = V_{DS}, I_{D}$ | = 250 μΑ | 0.45 | 0.76 | 1.1 | V |
| Negative Threshold Temperature Coefficient | V _{GS(TH)} /T _J | | | | -2.15 | | mV/°C |
| Drain-to-Source On Resistance | R _{DS(on)} | $V_{GS} = 4.5 \text{ V}, I_D$ | = 600 mA | | 127 | 230 | mΩ |
| | | $V_{GS} = 2.5 \text{ V}, I_D$ | = 500 mA | | 170 | 275 | - |
| | | V _{GS} = 1.8 V, I _D | = 350 mA | | 242 | 700 | |
| | | V _{GS} = 1.5 V, I _D = 40 mA | | | 500 | 950 | |
| Forward Transconductance | 9FS | $V_{DS} = 10 \text{ V}, I_D$ | = 400 mA | | 1.4 | | S |
| CHARGES AND CAPACITANCES | | | | | | | |
| Input Capacitance | C _{ISS} | | | | 110 | | pF |
| Output Capacitance | C _{OSS} | $V_{GS} = 0 \text{ V, f} = V_{DS} = 1$ | | | 16 | | |
| Reverse Transfer Capacitance | C _{RSS} | 100 | | | 12 | | |
| Total Gate Charge | Q _{G(TOT)} | | | | 1.82 | | nC |
| Threshold Gate Charge | Q _{G(TH)} | $V_{GS} = 4.5 \text{ V}, V_{I}$ | _{DS} = 10 V, | | 0.2 | | |
| Gate-to-Source Charge | Q_{GS} | $I_D = 0.2$ | Ā | | 0.3 | | |
| Gate-to-Drain Charge | Q_{GD} | | | | 0.42 | | |
| SWITCHING CHARACTERISTICS (No | te 3) | | | | | | |
| Turn-On Delay Time | t _{d(ON)} | | | | 3.7 | | ns |
| Rise Time | t _r | V_{GS} = 4.5 V, V_{DD} = 10 V, I_{D} = 0.2 A, R_{G} = 10 Ω | | | 4.4 | | |
| Turn-Off Delay Time | t _{d(OFF)} | | | | 25 | | |
| Fall Time | t _f | | | | 7.6 | | |
| DRAIN-SOURCE DIODE CHARACTE | RISTICS | | • | | | | _ |
| Forward Diode Voltage | V _{SD} | V _{GS} = 0 V, | T _J = 25°C | | 0.67 | 1.1 | V |
| | | $I_{S} = 200 \text{ mA}$ | | | 0.54 | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: pulse width $\leq 300 \ \mu s$, duty cycle $\leq 2\%$.

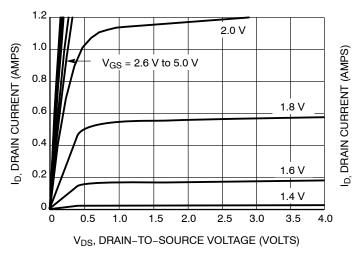
^{3.} Switching characteristics are independent of operating junction temperatures.

TYPICAL ELECTRICAL CHARACTERISTICS

1.2

1.0

 $V_{DS} \ge 10 \text{ V}$



0.8 0.6 0.4 0.2 0 0 0 0.4 0.8 1.2 1.6 2.0

V_{GS}, GATE-TO-SOURCE VOLTAGE (VOLTS)

Figure 1. On-Region Characteristics

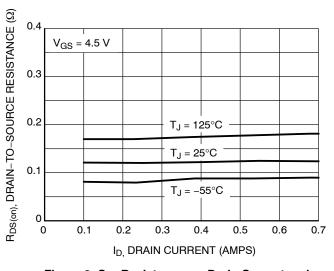


Figure 2. Transfer Characteristics

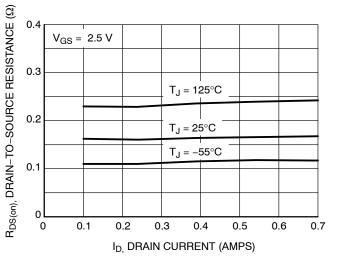


Figure 3. On–Resistance vs. Drain Current and Temperature

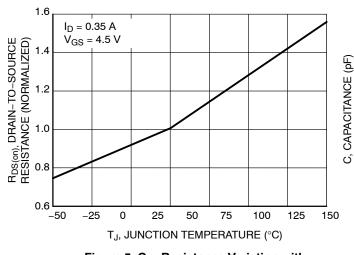


Figure 4. On-Resistance vs. Drain Current and Temperature

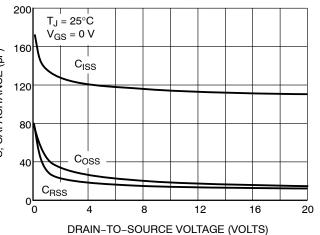


Figure 5. On–Resistance Variation with Temperature

Figure 6. Capacitance Variation

TYPICAL ELECTRICAL CHARACTERISTICS

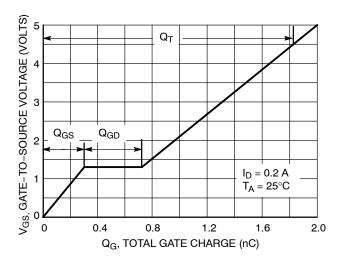


Figure 7. Gate-to-Source Voltage vs. Total Gate Charge

Figure 8. Diode Forward Voltage vs. Current

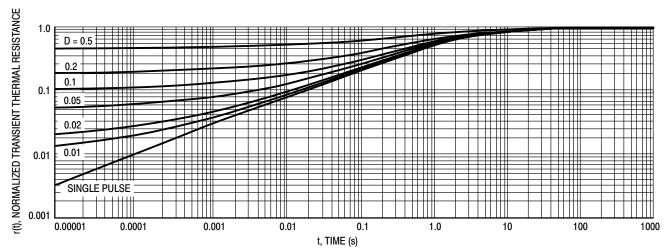


Figure 9. Normalized Thermal Response

ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|-------------|---------|------------------------------|-----------------------|
| NTA4153NT1 | TR | SC-75 / SOT-416 | 3000 / Tape & Reel |
| NTA4153NT1G | TR | SC-75 / SOT-416 (Pb-Free) | 3000 / Tape & Reel |
| NTE4153NT1G | TP | SC-89 (Pb-Free) | 3000 / Tape & Reel |
| NVA4153NT1G | VR | SC-75 / SOT-416 (Pb-Free) | 3000 / Tape & Reel |
| NVE4153NT1G | VP | SC-89 (Pb-Free) | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

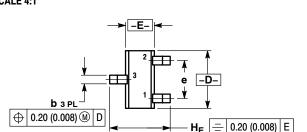
MECHANICAL CASE OUTLINE

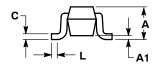




SC-75/SOT-416 CASE 463-01 ISSUE G

DATE 07 AUG 2015





STYLE 1: PIN 1. BASE 2. EMITTER

3. COLLECTOR

STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE

STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

| | MILLIMETERS | | | INCHES | ; | |
|-----|-------------|---------|------|----------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.70 | 0.80 | 0.90 | 0.027 | 0.031 | 0.035 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.15 | 0.20 | 0.30 | 0.006 | 0.008 | 0.012 |
| С | 0.10 | 0.15 | 0.25 | 0.004 | 0.006 | 0.010 |
| D | 1.55 | 1.60 | 1.65 | 0.061 | 0.063 | 0.065 |
| Е | 0.70 | 0.80 | 0.90 | 0.027 | 0.031 | 0.035 |
| е | 1 | .00 BSC |) | 0.04 BSC | | |
| L | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| HE | 1.50 | 1.60 | 1.70 | 0.060 | 0.063 | 0.067 |

GENERIC MARKING DIAGRAM*



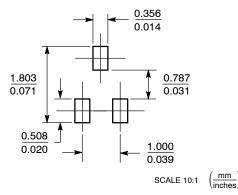
XX= Specific Device Code

Μ = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

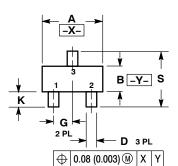
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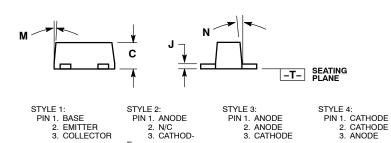
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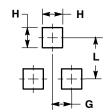


SC-89, 3 LEAD CASE 463C-03 ISSUE C

DATE 31 JUL 2003







RECOMMENDED PATTERN OF SOLDER PADS

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. 463C-01 OBSOLETE, NEW STANDARD 463C-02.

| | MILLIMETERS | | | | INCHES | |
|-----|-------------|----------|------|-------|---------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 |
| В | 0.75 | 0.85 | 0.95 | 0.030 | 0.034 | 0.040 |
| С | 0.60 | 0.70 | 0.80 | 0.024 | 0.028 | 0.031 |
| D | 0.23 | 0.28 | 0.33 | 0.009 | 0.011 | 0.013 |
| G | | .50 BS0 |) | 0 | .020 BS | С |
| Н | |).53 REF | | 0 | .021 RE | F |
| J | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| K | 0.30 | 0.40 | 0.50 | 0.012 | 0.016 | 0.020 |
| L | 1 | .10 REF | = | 0 | .043 RE | F |
| M | | | 10 | | | 10 |
| N | | | 10 - | | | 10 - |
| S | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 |

GENERIC MARKING DIAGRAM*



xx = Specific Device Code

= Date Code

*This information is generic. Please refer to device data sheet for actual part marking.

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|------------------|---------------|---|-------------|--|--|
| DESCRIPTION: | SC-89, 3 LEAD | | PAGE 1 OF 1 | | |

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